

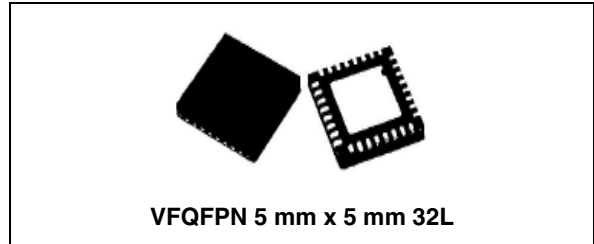
Push-pull four channel driver with diodes

Features

- 600 mA output current capability per channel
- 1.2 A peak output current (non repetitive) per channel
- Enable facility
- Overtemperature protection
- Logical "0" input voltage up to 1.5 V (high noise immunity)
- Internal clamp diodes

Description

The device is a monolithic integrated high voltage, high current four channel driver designed to accept standard DTL or TTL logic levels and drive inductive loads (such as relays solenoids, DC and stepping motors) and switching power transistors.

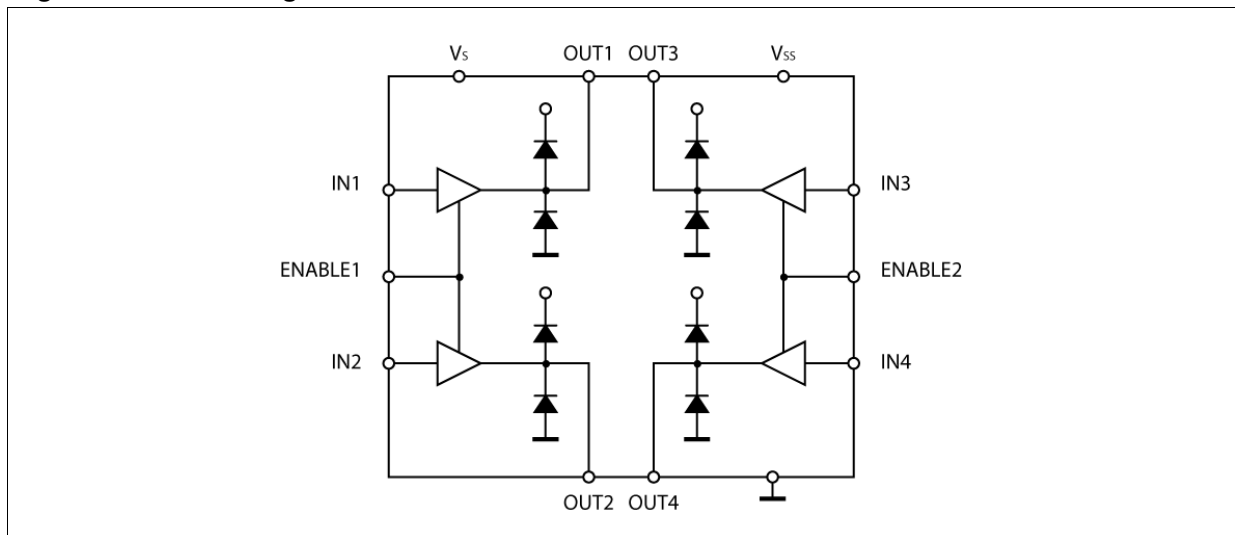


To simplify use as two bridges each pair of channels is equipped with an enable input. A separate supply input is provided for the logic, allowing operation at a lower voltage and internal clamp diodes are included.

This device is suitable for use in switching applications at frequencies up to 50 kHz.

The L2293Q is assembled in a VFQFPN-32L 5x5 package which has exposed pad available for heatsinking.

Figure 1. Block diagram



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1 Electrical data

1.1 Absolute maximum ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_S	Supply voltage	36	V
V_{SS}	Logic supply voltage	36	V
V_i	Input voltage	7	V
V_{en}	Enable voltage	7	V
I_o	Peak output current (100 μ s non repetitive)	1.2	A
P_{tot}	Total power dissipation at $T_{pins} = 90\text{ }^{\circ}\text{C}$	4	W
T_J	Junction temperature	150	$^{\circ}\text{C}$
T_{STG}	Storage temperature	– 40 to 150	$^{\circ}\text{C}$

1.2 Recommended conditions

Table 2. Recommended conditions

Symbol	Parameter	Value			Unit
		Min	Typ	Max	
V_S	Supply voltage	V_{SS}		36	V
V_{SS}	Logic supply voltage	2.8 ⁽¹⁾		36	V
T_J	Junction temperature	-20 ⁽¹⁾		125	$^{\circ}\text{C}$

1. See [Figure 2](#)

1.3 Thermal data

Figure 2. Typical minimum logic supply voltage vs junction temperature

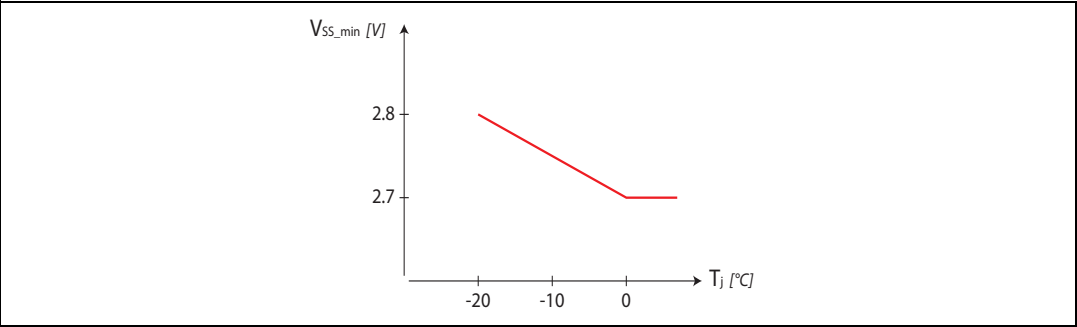


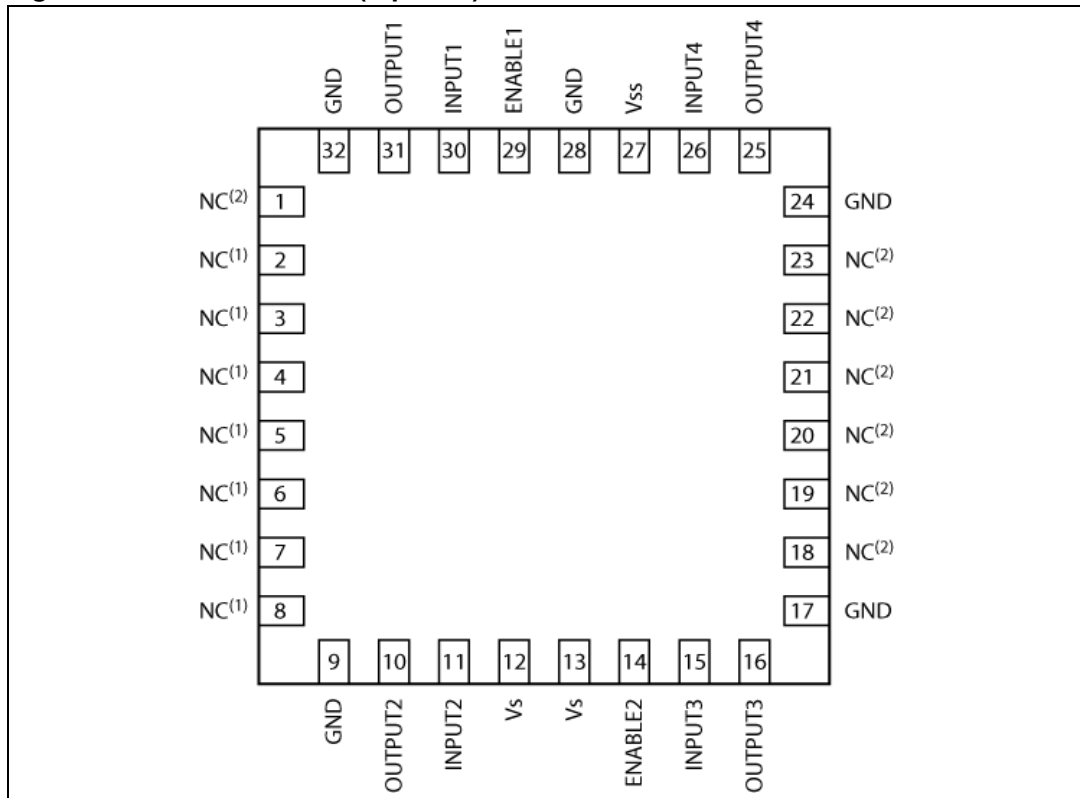
Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{th(JA)}$	Thermal resistance junction-ambient max. ⁽¹⁾	42	$^{\circ}C/W$

1. Mounted on a double-layer FR4 PCB with a dissipating copper surface of 0.5 cm² on the top side plus 6 cm² ground layer connected through 18 via holes (9 below the IC).

2 Pin connection

Figure 2. Pin connection (top view)



Note:

$NC^{(1)}$ These NC pins are connected to the exposed PAD.

The exposed PAD must be connected to GND pins.

$NC^{(2)}$ These NC pins can be connected to GND pins and exposed PAD.

Figure 3. Recommended PCB layout for $R_{th(JA)}$ optimization

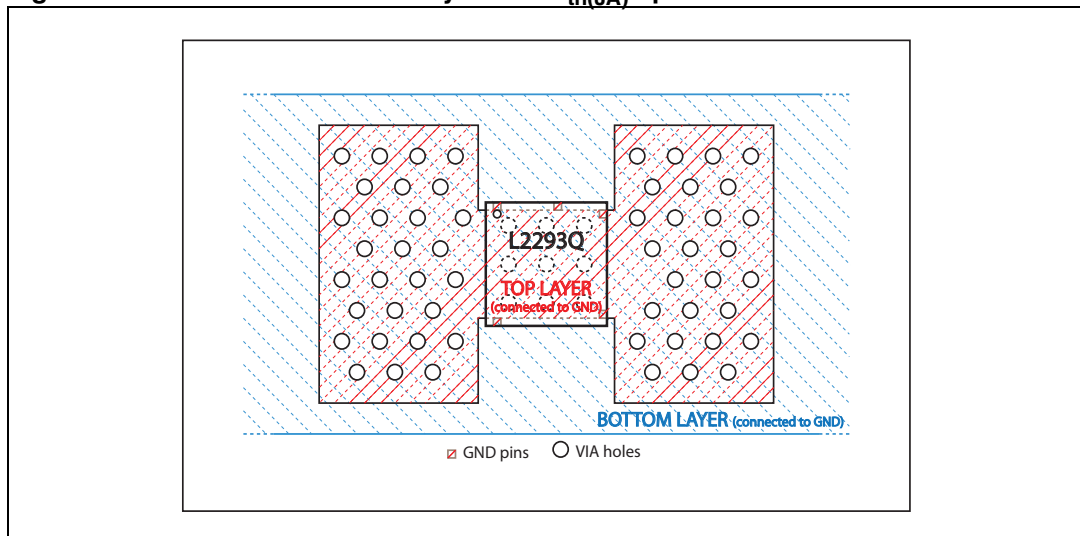


Table 4. Pin description

Pin n°	Name	Type	Function
1, 18, 19, 20, 21, 22, 23	NC		Not connected
2, 3, 4, 5, 6, 7,	NC		Pins connected to the exposed PAD
8, 9, 17, 24, 28, 32	GND		Ground
10	OUTPUT2	O	Output 2
11	INPUT2	I	Input 2
12, 13	V _S		Supply voltage for the power output stages. A non-inductive 100 nF capacitor must be connected between these pins and ground.
14	ENABLE2	I	Enable 2 input, the LOW state disables the Output 3 and Output 4.
15	INPUT3	I	Input 3
16	OUTPUT3	O	Output 3
25	OUTPUT4	O	Output 4
26	INPUT4	I	Input 4
27	V _{SS}		Supply voltage for the logic blocks. A 100 nF capacitor must be connected between this pin and ground.
29	ENABLE1	I	Enable 1 input, the LOW state disables the output 1 and Output 2.
30	INPUT1	I	Input 1
31	OUTPUT1	O	Output 1

3 Electrical characteristics

For each channel, $V_S = 24\text{ V}$, $V_{SS} = 5\text{ V}$, $T_A = 25\text{ }^\circ\text{C}$, unless otherwise specified.

Table 5. Electrical characteristics

Symbol	Pin	Parameter	Test condition	Min	Typ	Max	Unit
I_S	12, 13	Total quiescent supply current	$V_i = L; I_O = 0; V_{en} = H$		2	6	mA
			$V_i = H; I_O = 0; V_{en} = H$		16	24	mA
			$V_{en} = L$			4	mA
I_{SS}	27	Total quiescent logic supply current	$V_i = L; I_O = 0; V_{en} = H$		44	60	mA
			$V_i = H; I_O = 0; V_{en} = H$		16	22	mA
			$V_{en} = L$		16	24	mA
V_{IL}	11, 15, 26, 30	Input low voltage		- 0.3		1.5	V
V_{IH}	11, 15, 26, 30	Input high voltage	$V_{SS} \leq 7\text{ V}$	2.3		V_{SS}	V
			$V_{SS} > 7\text{ V}$	2.3		7	V
I_{IL}	11, 15, 26, 30	Low voltage input current	$V_{IL} = 1.5\text{ V}$			- 10	μA
I_{IH}	11, 15, 26, 30	High voltage input current	$2.3\text{ V} \leq V_{IH} \leq V_{SS} - 0.6\text{ V}$		30	100	μA
$V_{en L}$	14, 29	Enable low voltage		- 0.3		1.5	V
$V_{en H}$	14, 29	Enable high voltage	$V_{SS} \leq 7\text{ V}$	2.3		V_{SS}	V
			$V_{SS} > 7\text{ V}$	2.3		7	V
$I_{en L}$	14, 29	Low voltage enable current	$V_{en L} = 1.5\text{ V}$		- 30	- 100	μA
$I_{en H}$	14, 29	High voltage enable current	$2.3\text{ V} \leq V_{en H} \leq V_{SS} - 0.6\text{ V}$			± 10	μA
$V_{CE(sat)H}$	10, 16, 25, 31	Source output saturation voltage	$I_O = - 0.6\text{ A}$		1.4	1.8	V
$V_{CE(sat)L}$	10, 16, 25, 31	Sink output saturation voltage	$I_O = + 0.6\text{ A}$		1.2	1.8	V
V_F		Clamp diode forward voltage	$I_O = 600\text{ nA}$		1.3		V

$V_S = 24\text{ V}$, $V_{SS} = 5\text{ V}$, $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified.

Table 6. AC operation

Symbol	Parameter	Test condition	Min	Typ	Max	Unit
t_r	Rise time ⁽¹⁾	0.1 to 0.9 V_O		250		ns
t_f	Fall time ⁽¹⁾	0.9 to 0.1 V_O		250		ns
t_{on}	Turn-on delay ⁽¹⁾	0.5 V_i to 0.5 V_O		750		ns
t_{off}	Turn-off delay ⁽¹⁾	0.5 V_i to 0.5 V_O		200		ns

1. See [Figure 4](#)

Figure 4. Switching times

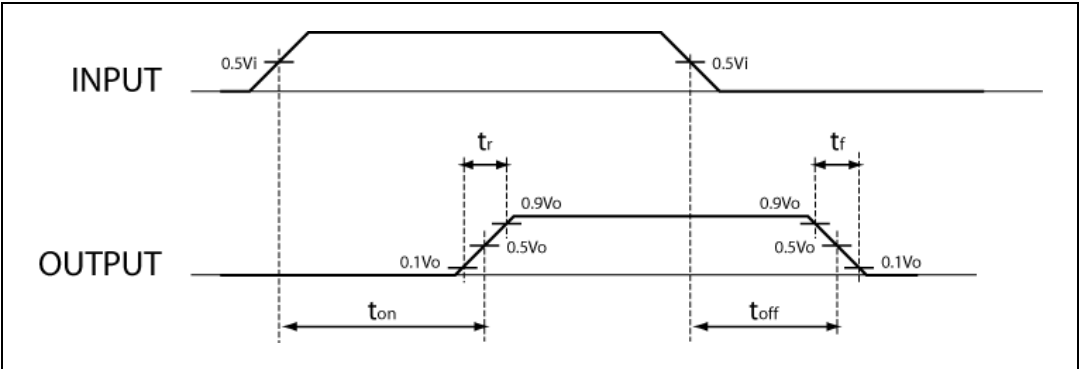


Table 7. Truth table (one channel)

Input	Enable ⁽¹⁾	Output
H	H	H
L	H	L
H	L	Z ⁽²⁾
L	L	Z ⁽²⁾

- 1. Relative to the considered channel
- 2. Z = High output impedance

4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Table 8. VFQFPN 5x5x1.0 32L pitch 0.50

Dim.	Databook (mm)		
	Min	Typ	Max
A	0.80	0.85	0.95
b	0.18	0.25	0.30
b1	0.165	0.175	0.185
D	4.85	5.00	5.15
D2	3.00	3.10	3.20
D3	1.10	1.20	1.30
E	4.85	5.00	5.15
E2	4.20	4.30	4.40
E3	0.60	0.70	0.80
e		0.50	
L	0.30	0.40	0.50
ddd			0.08

- Note:**
- 1 VFQFPN stands for thermally enhanced very thin profile fine pitch quad flat package no lead. Very thin profile: $0.80 < A \leq 1.00$ mm.
 - 2 Details of terminal 1 are optional but must be located on the top surface of the package by using either a mold or marked features.

VFQFPN 5x5x1.0 32L PITCH 0.50 (UTAC Thai SUBCON.) Special design

The drawing illustrates the mechanical specifications of a VFQFPN 5x5x1.0 32L PITCH 0.50 package. The top view shows a square footprint with dimensions D (width) and E (height). The package has a central square area with a crosshair. The bottom view shows the package mounted on a substrate, with dimensions D2, D3, and D4 indicating the footprint. The package is labeled with 'C' and 'ddd' on the top surface. The package is shown in a side view, indicating a height of 1.0 mm. The package is shown in a bottom view, indicating a pitch of 0.50 mm. The package is shown in a side view, indicating a pitch of 0.50 mm. The package is shown in a bottom view, indicating a pitch of 0.50 mm.

5 Order codes

Table 9. Order code

Order code	Package	Packaging
L2293Q	VFQFPN 5x5x1.0 32L	Tube

6 Revision history

Table 10. Document revision history

Date	Revision	Changes
10-Jul-2008	1	First release
26-Feb-2009	2	Updated Table 3 on page 4
12-Aug-2009	3	Updated description in coverpage

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